

TC74VHC132F, TC74VHC132FN, TC74VHC132FS, TC74VHC132FT

QUAD 2-INPUT SCHMITT NAND GATE

The TC74VHC132 is an advanced high speed CMOS 2-INPUT SCHMITT NAND GATE fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

Pin configuration and function are the same as the TC74VHC00 but the inputs have hysteresis and with its schmitt trigger function, the TC74VHC132 can be used as a line receivers which will receive slow input signals.

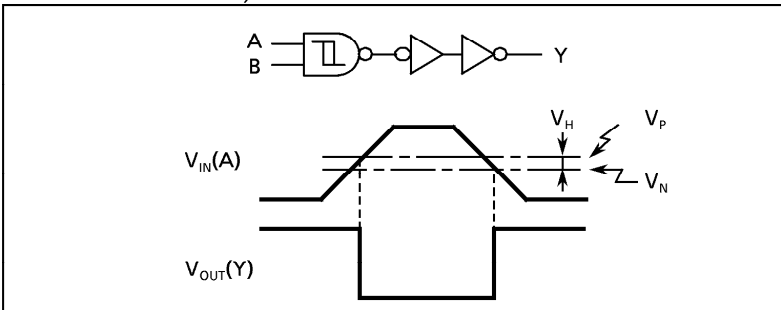
An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up.

This circuit prevents device destruction due to mismatched supply and input voltages.

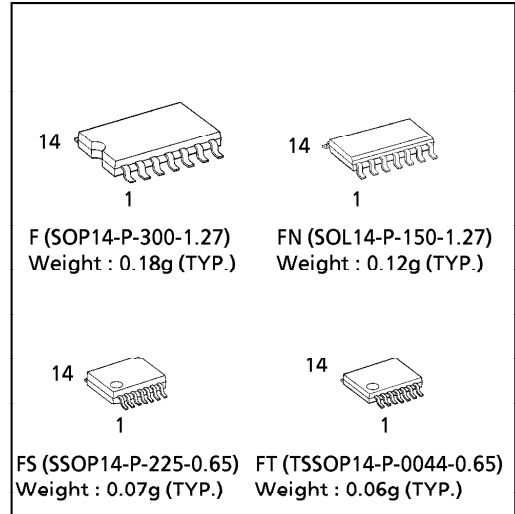
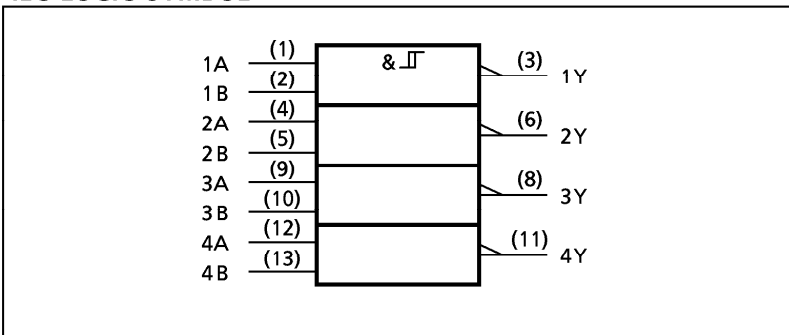
FEATURES :

- High Speed..... $t_{pd} = 4.9ns(typ.)$ at $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 2\mu A(Max.)$ at $T_a = 25^\circ C$
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range..... $V_{CC} (opr) = 2V \sim 5.5V$
- Low Noise..... $V_{OLP} = 0.8V (Max.)$
- Pin and Function Compatible with 74ALS132

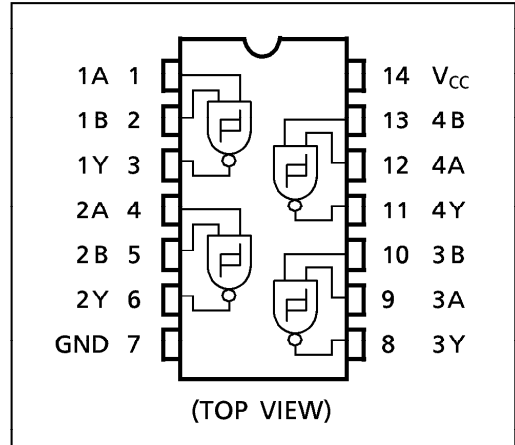
SYSTEM DIAGRAM, WAVEFORM



IEC LOGIC SYMBOL



PIN ASSIGNMENT



TRUTH TABLE

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

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ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC} /Ground Current	I_{CC}	±50	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	-65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
Positive Threshold Voltage	V_P		3.0	—	—	2.20	—	2.20	V	
			4.5	—	—	3.15	—	3.15		
			5.5	—	—	3.85	—	3.85		
Negative Threshold Voltage	V_N		3.0	0.90	—	—	0.90	—	V	
			4.5	1.35	—	—	1.35	—		
			5.5	1.65	—	—	1.65	—		
Hysteresis Output Voltage	V_H		3.0	0.30	—	1.20	0.30	1.20	V	
			4.5	0.40	—	1.40	0.40	1.40		
			5.5	0.50	—	1.60	0.50	1.60		
High - Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\mu A$	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0	2.58	—	—	2.48	—	
				4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 50\mu A$	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			$I_{OL} = 4mA$ $I_{OL} = 8mA$	3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	$V_{IN} = 5.5V$ or GND	0~5.5	—	—	±0.1	—	±1.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND	5.5	—	—	2.0	—	20.0		

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AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT
		V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time	t_{pLH} t_{pHL}	3.3 ± 0.3	15	—	7.6	11.9	1.0	14.0	ns
			50	—	10.1	15.4	1.0	17.5	
		5.0 ± 0.5	15	—	4.9	7.7	1.0	9.0	
			50	—	6.4	9.7	1.0	11.0	
Input Capacitance	C _{IN}			—	4	10	—	10	pF
Power Dissipation Capacitance	C _{PD}	(Note 1)		—	16	—	—	—	

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

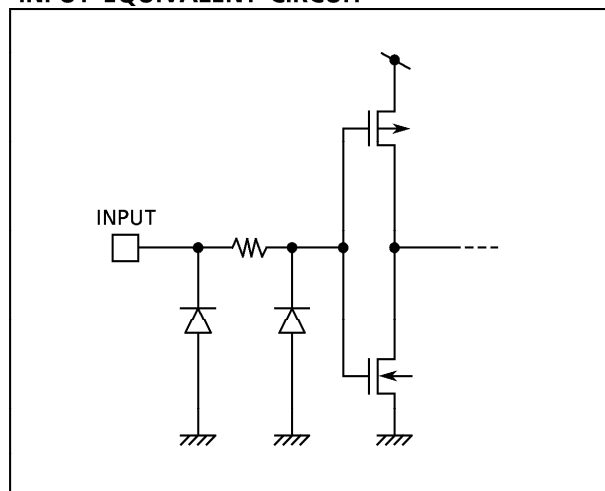
Average operating current can be obtained by the equation :

$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 4 \text{ (per Gate.)}$$

NOISE CHARACTERISTICS (Input $t_r = t_f = 3ns$)

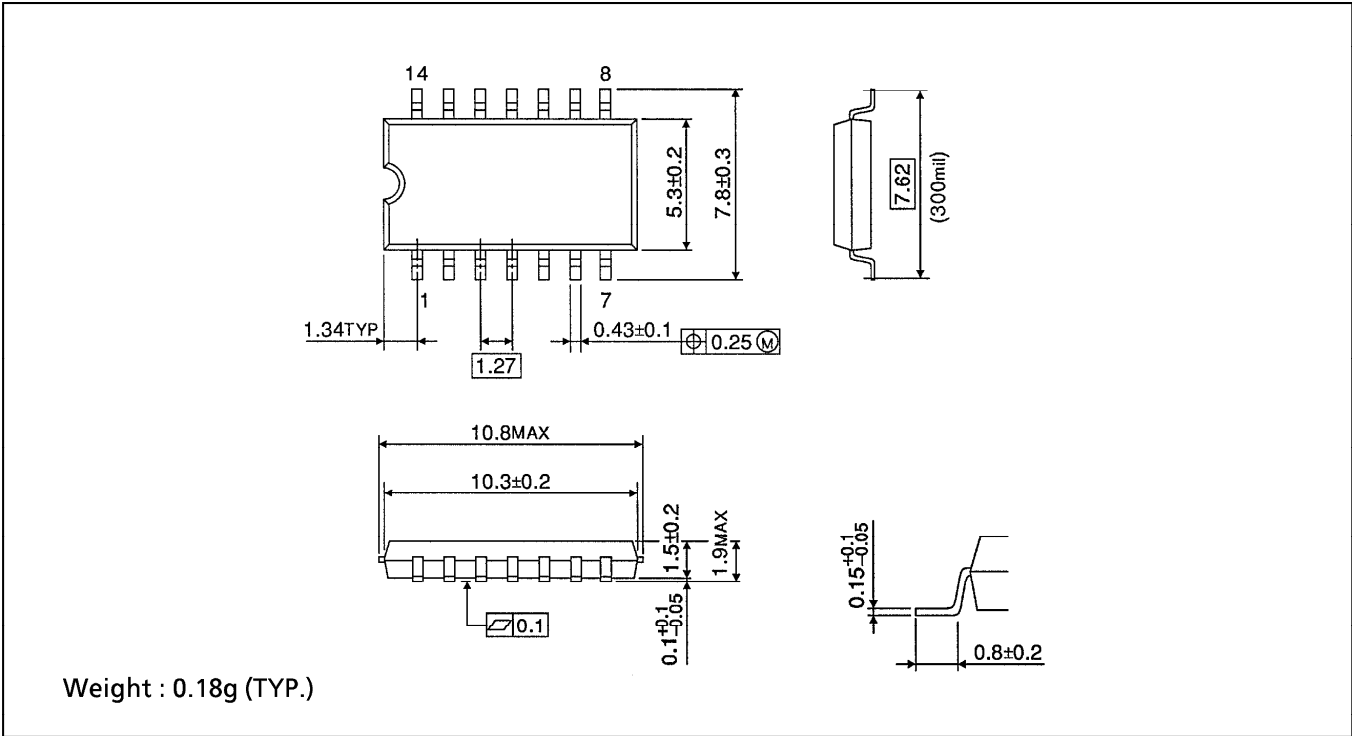
PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C		UNIT	
			V _{CC} (V)	TYP.		MAX.
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	C _L = 50pF	5.0	0.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	C _L = 50pF	5.0	-0.3	-0.8	V
Minimum High Level Dynamic Input Voltage	V _{IHD}	C _L = 50pF	5.0	—	3.5	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}	C _L = 50pF	5.0	—	1.5	V

INPUT EQUIVALENT CIRCUIT



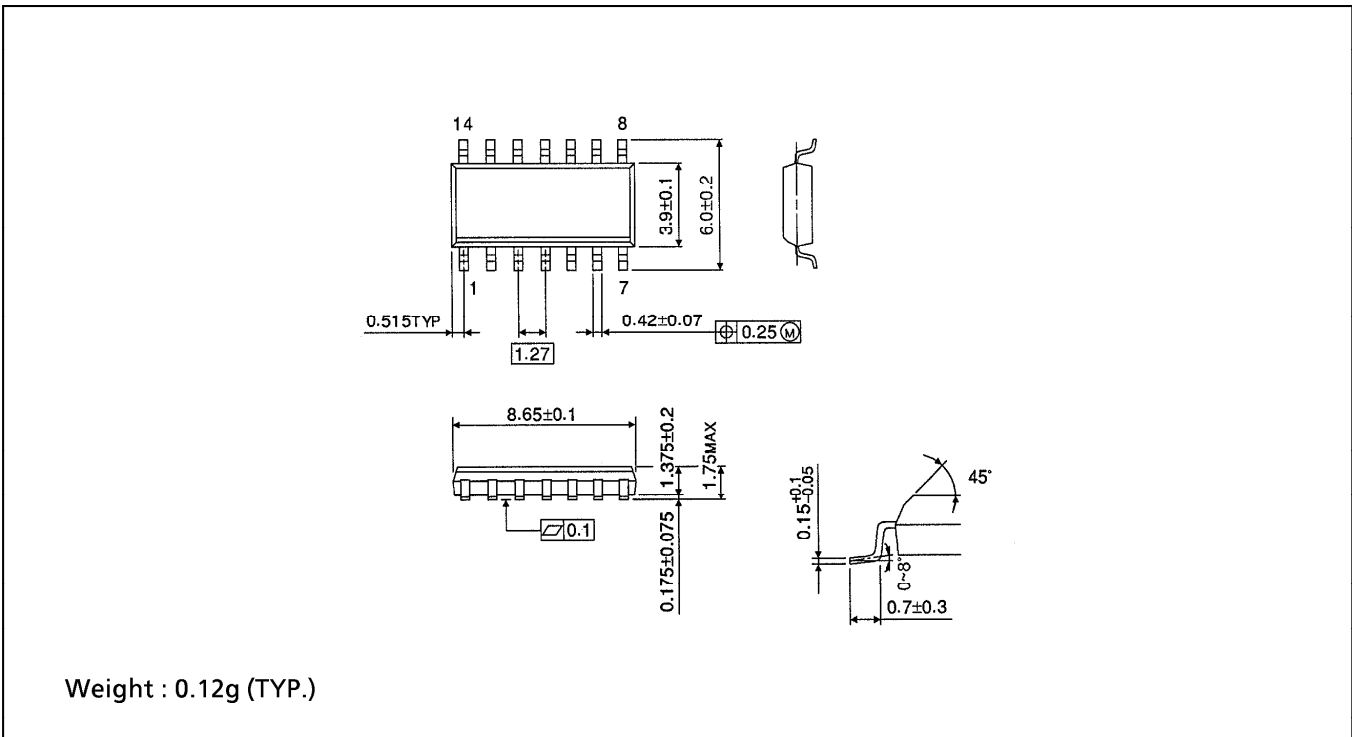
SOP 14PIN (200mil BODY) OUTLINE DRAWING (SOP14-P-300-1.27)

Unit in mm



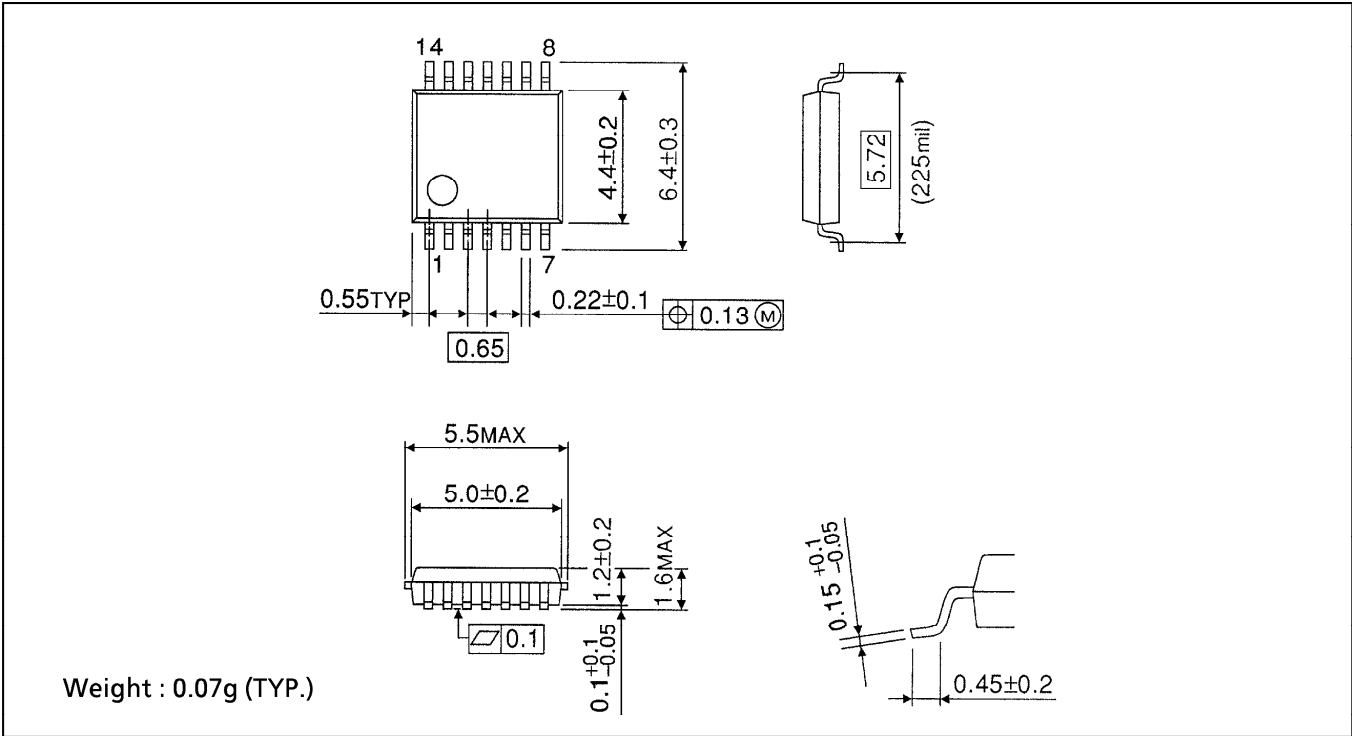
SOP 14PIN (150mil BODY) OUTLINE DRAWING (SOP14-P-150-1.27)

Unit in mm



SSOP 14PIN OUTLINE DRAWING (SSOP14-P-225-0.65)

Unit in mm



TSSOP 14PIN OUTLINE DRAWING (TSSOP14-P-0044-0.65)

Unit in mm

